# SCS308AM

## SiC Schottky Barrier Diode

Datasheet

$V_R$	650V
I <sub>F</sub>	8A
$Q_{C}$	21nC

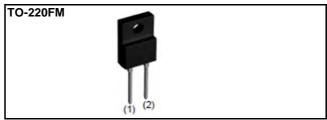
#### Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible
- 4) High surge current capability

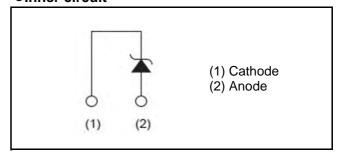
### Applications

- PFC Boost Topology
- · Secondary Side Rectification
- Data Center
- PV Power Conditioners

#### Outline



#### •Inner circuit



Packaging specifications

	ging opcomouncine	
	Packaging	Tube
	Reel size (mm)	-
Typo	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS308AM

#### ● Absolute maximum ratings (T<sub>i</sub> = 25°C)

	Parameter	Symbol	Value	Unit
Reverse voltage (re	petitive peak)	$V_{RM}$	650	V
Reverse voltage (De	C)	V <sub>R</sub>	650	V
Continuous forward	current (T <sub>c</sub> = 105°C)	I <sub>F</sub>	8	А
Surge non-	PW=10ms sinusoidal, T <sub>j</sub> =25°C	I <sub>FSM</sub>	67	А
repetitive forward	PW=10ms sinusoidal, T <sub>j</sub> =150°C		57	А
current	PW=10μs square, T <sub>j</sub> =25°C		250	А
Repetitive peak forv	vard current	I <sub>FRM</sub>	27 <sup>*1</sup>	А
1≦PW≦10ms, T <sub>j</sub> =25°C		$\int i^2 dt$	22	A <sup>2</sup> s
i <sup>2</sup> t value	1≦PW≦10ms, T <sub>j</sub> =150°C	J 1⁻at	16	A <sup>2</sup> s
Total power disspat	ion	$P_{D}$	33 *²	W
Junction temperatur	re	$T_j$	175	°C
Range of storage te	mperature	$T_{stg}$	-55 to +175	°C

<sup>\*1</sup> T<sub>c</sub>=100°C, T<sub>i</sub>=150°C, Duty cycle=10% \*2 T<sub>c</sub>=25°C

# •Electrical characteristics $(T_j = 25^{\circ}C)$

Parameter	Symbol	Conditions	Values			Unit
Parameter			Min.	Тур.	Max.	Unit
DC blocking voltage	$V_{DC}$	I <sub>R</sub> =40μA	650	-	-	V
	V <sub>F</sub>	I <sub>F</sub> =8A,T <sub>j</sub> =25°C	-	1.35	1.50	V
Forward voltage		I <sub>F</sub> =8A,T <sub>j</sub> =150°C	-	1.44	1.71	V
		I <sub>F</sub> =10A,T <sub>j</sub> =175°C	-	1.50	-	V
	I <sub>R</sub>	V <sub>R</sub> =650V,T <sub>j</sub> =25°C	-	0.024	40	μΑ
Reverse current		V <sub>R</sub> =650V,T <sub>j</sub> =150°C	-	1.6	160	μΑ
		V <sub>R</sub> =650V,T <sub>j</sub> =175°C	-	4.8	-	μΑ
Total conscitous	С	V <sub>R</sub> =1V,f=1MHz	-	400	-	pF
Total capacitance		V <sub>R</sub> =650V,f=1MHz	-	36	-	pF
Total capacitive charge	Q <sub>C</sub>	V <sub>R</sub> =400V,di/dt=350A/μs	-	21	-	nC
Switching time	t <sub>C</sub>	V <sub>R</sub> =400V,di/dt=350A/μs	-	15	-	ns
Non-repetetive Avaranche Energy	E <sub>ava</sub>	L=1mH	-	110	-	mJ

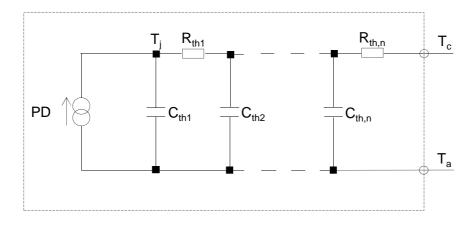
#### Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
	Symbol		Min.	Тур.	Max.	UIIIL
Thermal resistance	$R_{th(j-c)}$	-	-	3.9	4.5	°C/W

## ●Typical Transient Thermal Characteristics

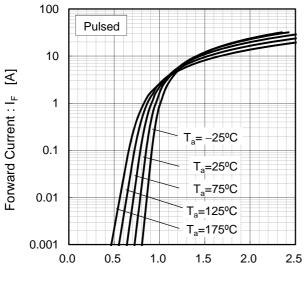
<u> </u>		
Symbol	Value	Unit
R <sub>th1</sub>	2.15E-01	
$R_{th2}$	1.40E+00	K/W
R <sub>th3</sub>	2.28E+00	

Symbol	Value	Unit
$C_{th1}$	2.62E-04	
$C_{th2}$	2.27E-03	Ws/K
C <sub>th3</sub>	3.28E-01	



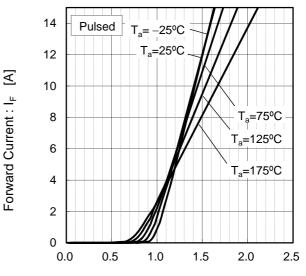
#### •Electrical characteristic curves

Fig.1 V<sub>F</sub> - I<sub>F</sub> Characteristics



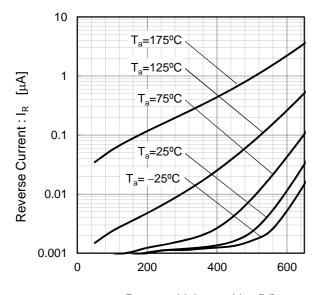
Forward Voltage: V<sub>F</sub> [V]

Fig.2 V<sub>F</sub> - I<sub>F</sub> Characteristics



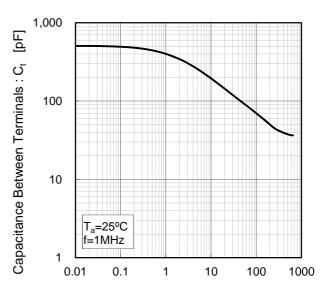
Forward Voltage : V<sub>F</sub> [V]

Fig.3  $V_R$  -  $I_R$  Characteristics



Reverse Voltage : V<sub>R</sub> [V]

Fig.4 V<sub>R</sub>-C<sub>t</sub> Characteristics



Reverse Voltage: V<sub>R</sub> [V]

#### •Electrical characteristic curves

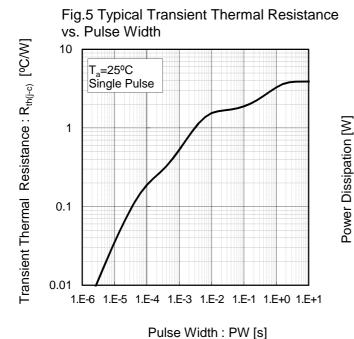
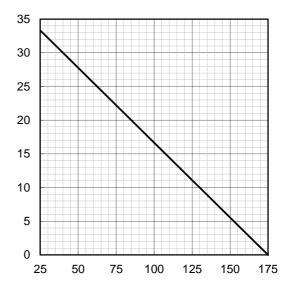
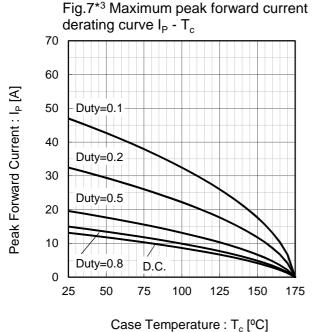


Fig.6 Power Dissipation



Case Temperature : T<sub>c</sub> [°C]



Peak Forward Current : I<sub>P</sub> [A]

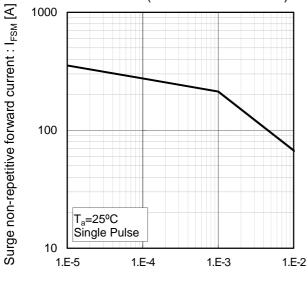
derating curve I<sub>P</sub> - T<sub>c</sub> (Not guaranteed) 70 Duty=0.1 60 50 Duty=0.2 40 30 Duty=0.5 20 10 Duty=0.8 D.C. 0 25 50 75 100 125 150 175

Fig.8\*4 Typical peak forward current

Case Temperature : T<sub>c</sub> [°C]
\*4 Based on typ Vf, typ R<sub>th(j-c)</sub>
Typical value, not guaranteed
Valid for switching of above 10kHz,
excluding D.C. curve

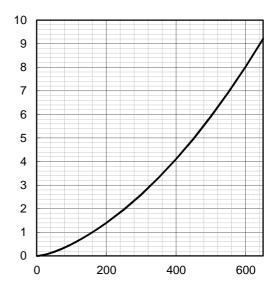
#### •Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

Fig.10 Typical capacitance store energy

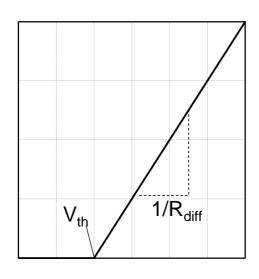


Capacitance stored energy :  $E_{\rm C}[\mu J]$ 

Reverse Voltage: V<sub>R</sub> [V]

#### Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V<sub>F</sub>

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th} \left( \ T_{j} \ \right) = a_{0} + a_{1} \, T_{j} \\ &R_{diff} \left( \ T_{j} \ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
<b>a</b> <sub>0</sub>	9.66E-01	V
a <sub>1</sub>	-1.10E-03	V/°C
b <sub>0</sub>	4.40E-02	Ω
b <sub>1</sub>	9.33E-05	Ω/°C
b <sub>2</sub>	9.60E-07	$\Omega$ /°C <sup>2</sup>

 $T_i \text{ in } {}^{\circ}\text{C}; -55 {}^{\circ}\text{C} < T_i < 175 {}^{\circ}\text{C}; I_F < 16 \text{ A}$ 

Forward Current: IF

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